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SLFS023G-APRIL 1978-REVISED JUNE 2006

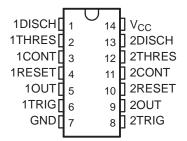
#### **FEATURES**

- Two Precision Timing Circuits Per Package
- Astable or Monostable Operation
- TTL-Compatible Output Can Sink or Source up to 150 mA
- Active Pullup or Pulldown
- Designed to Be Interchangeable With Signetics NE556, SA556, and SE556

#### **APPLICATIONS**

- Precision Timers From Microseconds to Hours
- Pulse-Shaping Circuits
- Missing-Pulse Detectors
- Tone-Burst Generators
- Pulse-Width Modulators
- Pulse-Position Modulators
- Sequential Timers
- Pulse Generators
- Frequency Dividers
- Application Timers
- Industrial Controls
- Touch-Tone Encoders

NA556...D OR N PACKAGE NE556...D, N, OR NS PACKAGE SA556...D OR N PACKAGE SE556...J PACKAGE (TOP VIEW)



### **DESCRIPTION/ORDERING INFORMATION**

These devices provide two independent timing circuits of the NA555, NE555, SA555, or SE555 type in each package. These circuits can be operated in the astable or the monostable mode with external resistor-capacitor (RC) timing control. The basic timing provided by the RC time constant can be controlled actively by modulating the bias of the control-voltage input.

The threshold (THRES) and trigger (TRIG) levels normally are two-thirds and one-third, respectively, of  $V_{CC}$ . These levels can be altered by using the control voltage (CONT) terminal. When the trigger input falls below trigger level, the flip-flop is set and the output goes high. If the trigger input is above the trigger level and the threshold input is above the threshold level, the flip-flop is reset, and the output is low. The reset (RESET) input can override all other inputs and can be used to initiate a new timing cycle. When RESET goes low, the flip-flop is reset and the output goes low. When the output is low, a low-impedance path is provided between the discharge (DISCH) terminal and ground (GND).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



#### **ORDERING INFORMATION**

T <sub>A</sub>	V <sub>T</sub> (MAX) V <sub>CC</sub> = 15 V	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
		PDIP – N	Tube of 25	NE556N	NE556N	
0°C to 70°C	11.2 V	SOIC - D	Tube of 50	NE556D	NE556	
0.0 10 10.0	11.2 V	30IC - D	Reel of 2500	NE556DR	INESSO	
		SOP - NS	Reel of 2000	NE556NSR	NE556	
-40°C to 85°C	11.2 V	PDIP – N	Tube of 25	SA556N	SA556N	
		PDIP – N	Tube of 25	NA556N	NA556N	
-40°C to 105°C	11.2 V	SOIC - D	Tube of 50	NA556D	NA556	
		30IC - D	Reel of 2500	NA556DR	INASSO	
–55°C to 125°C	10.6 V	CDIP – J	Tube of 25	SE556J	SE556J	
-55 C to 125°C	10.6 V	CDIF – J	Tube Of 25	SE556JB	SE556JB	

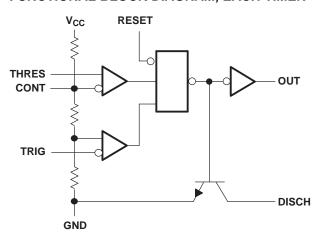
<sup>(1)</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

# FUNCTION TABLE (each timer)

RESET	TRIGGER VOLTAGE <sup>(1)</sup>	THRESHOLD VOLTAGE <sup>(1)</sup>	ОИТРИТ	DISCHARGE SWITCH
Low	Irrelevant	Irrelevant	Low	On
High	<1/3 V <sub>DD</sub>	Irrelevant	High	Off
High	>1/3 V <sub>DD</sub>	>2/3 V <sub>DD</sub>	Low	On
High	>1/3 V <sub>DD</sub>	<2/3 V <sub>DD</sub>	As previou	sly established

(1) Voltage levels shown are nominal.

## **FUNCTIONAL BLOCK DIAGRAM, EACH TIMER**



RESET can override TRIG, which can override THRES.



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage <sup>(2)</sup>			18	V
VI	Input voltage	CONT, RESET, THRES, and TRIG		V <sub>CC</sub>	V
Io	Output current			±225	mA
		D package		86	
$\theta_{JA}$	Package thermal impedance (3)(4)	N package		80	°C/W
		D package N package NS package J package		76	
$\theta_{\text{JC}}$	Package thermal impedance (5)(6)	J package		15.05	°C/W
TJ	Operating virtual junction temperature			150	°C
	Lead temperature 1,6 mm (1/16 in) from case for 60 s	J package		300	°C
	Lead temperature 1,6 mm (1/16 in) from case for 10 s	D, N, or NS package		260	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

- Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- All voltage values are with respect to network ground terminal. Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.
- Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JC}$ , and  $T_C$ . The maximum allowable power dissipation at any allowable case temperature is  $P_D = (T_J(max) T_C)/\theta_{JC}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.
- The package thermal impedance is calculated in accordance with MIL-STD-883.

## **Recommended Operating Conditions**

			MIN	MAX	UNIT
1/	Cupply valtage	NA556, NE556, SA556	4.5	16	V
$V_{CC}$	Supply voltage	SE556	4.5	18	V
VI	Input voltage	CONT, RESET, THRES, and TRIG		V <sub>CC</sub>	V
Io	Output current			±200	mA
		NA556	-40	105	
т	Operating free air temperature	NE556	0	70	°C
IA	Operating free-air temperature	SA556	-40	85	٠.
		SE556	-55	125	



## **Electrical Characteristics**

 $V_{\rm CC}$  = 5 V to 15 V,  $T_{\rm A}$  = 25°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS		NA556 NE556 SA556				UNIT					
						MAX	MIN	TYP	MAX				
. ,	Threshold voltage	V <sub>CC</sub> = 15 V		8.8	10	11.2	9.4	10	10.6				
$V_T$	level	V <sub>CC</sub> = 5 V		2.4	3.3	4.2	2.7	3.3	4	V			
I <sub>T</sub>	Threshold current <sup>(1)</sup>				30	250		30	250	nA			
		\/ 4E\/		4.5	5	5.6	4.8	5	5.2				
V	Trigger veltage level	$V_{CC} = 15 \text{ V}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$				3		6	\/			
$V_{TRIG}$	Trigger voltage level	\/ _ F \/		1.1	1.67	2.2	1.45	1.67	1.9	V			
	$V_{CC} = 5 V$	$T_A = -55^{\circ}C$ to $125^{\circ}C$						1.9					
$I_{TRIG}$	Trigger current	TRIG at 0 V			0.5	2		0.5	0.9	μΑ			
V	Poset veltage level			0.3	0.7	1	0.3	0.7	1	V			
V <sub>RESET</sub>	Reset voltage level	$T_A = -55^{\circ}C \text{ to } 12^{\circ}$	25°C						1.1	V			
	Reset current	RESET at V <sub>CC</sub>			0.1	0.4		0.1	0.4	mA			
I <sub>RESET</sub>	Neset Current	RESET at 0 V			-0.4	1.5		-0.4	-1	ША			
I <sub>DISCH</sub>	Discharge switch off-state current				20	100		20	100	nA			
		V - 15 V		9	10	11	9.6	10	10.4				
W	Control voltage	V <sub>CC</sub> = 15 V	$T_A = -55^{\circ}C$ to 125°C				9.6		10.4	V			
$V_{CONT}$	v con (open circuit)	\/ _ F \/		2.6	3.3	4	2.9	3.3	3.8	V			
	$V_{CC} = 5 V$	$T_A = -55^{\circ}C$ to $125^{\circ}C$				2.9		3.8					
	V <sub>CC</sub> = 15 V,			0.1	0.25		0.1	0.15					
		$I_{OL} = 10 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$						0.2				
		V <sub>CC</sub> = 15 V,			0.4	0.75		0.4	0.5				
		$I_{OL} = 50 \text{ mA}$	$T_A = -55^{\circ}C$ to $125^{\circ}C$						1				
		V <sub>CC</sub> = 15 V,			2	2.5		2	2.2				
$V_{OL}$	Low-level	$I_{OL} = 100 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$						2.7	V			
· OL	output voltage	$V_{CC}$ = 15 V, $I_{OL}$	= 200 mA		2.5			2.5		•			
		$V_{CC} = 5 \text{ V},$ $I_{OL} = 3.5 \text{ mA}$	$T_A = -55^{\circ}C$ to 125°C						0.35				
		$V_{CC} = 5 V$ ,			0.1	0.25		0.1	0.15				
		$I_{OL} = 5 \text{ mA}$	$T_A = -55^{\circ}C$ to $125^{\circ}C$						8.0				
		$V_{CC} = 5 \text{ V}, I_{OL} =$	8 mA		0.15	0.3		0.15	0.25				
		$V_{CC} = 15 \text{ V},$		12.75	13.3		13	13.3					
		$I_{OH} = -100 \text{ mA}$	$T_A = -55^{\circ}C \text{ to } 125^{\circ}C$				12						
$V_{OH}$	High-level output voltage	$V_{CC}$ = 15 V, $I_{OH}$	= –200 mA		12.5			12.5		V			
		V <sub>CC</sub> = 5 V,		2.75	3.3		3	3.3	-				
		$I_{OH} = -100 \text{ mA}$	$T_A = -55^{\circ}C$ to $125^{\circ}C$				2						
		Output low,	V <sub>CC</sub> = 15 V		20	30		20	24				
1	Supply ourrent	No load	V <sub>CC</sub> = 5 V		6	12		6	10	mA			
I <sub>CC</sub>	Supply current	Output high,	V <sub>CC</sub> = 15 V		18	26		18	20				
			V <sub>CC</sub> = 5 V		4	10		4	8				

<sup>(1)</sup> This parameter influences the maximum value of the timing resistors R and R<sub>B</sub> in the circuit of Figure 1. For example, when  $V_{CC}$  = 5 V, the maximum value is R = R<sub>A</sub> + R<sub>B</sub>  $\approx$  3.4 M $\Omega$ , and for V<sub>CC</sub> = 15 V, the maximum value is  $\approx$  10 M $\Omega$ .



## **Operating Characteristics**

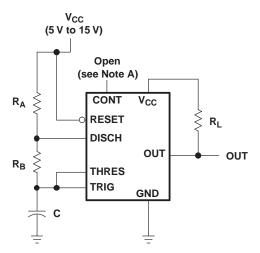
 $V_{CC} = 5 \text{ V} \text{ and } 15 \text{ V}$ 

PARAMETER		TEST CONDITIONS <sup>(1)</sup>	NA556 NE556 SA556			SE556			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
Initial error of timing	Each timer, monostable <sup>(3)</sup>			1	3		0.5	1.5 <sup>(4)</sup>	
interval <sup>(2)</sup>	Each timer, astable <sup>(5)</sup>	T <sub>A</sub> = 25°C		2.25%			1.5%		
	Timer 1 – Timer 2			±1			±0.5		
Temperature	Each timer, monostable <sup>(3)</sup>			50			30	100(4)	
coefficient of timing interval	Each timer, astable (5)	$T_A = MIN \text{ to } MAX$		150			90		ppm/°C
morvai	Timer 1 – Timer 2			±10			±10		
Supply voltage	Each timer, monostable <sup>(3)</sup>			0.1	0.5		0.05	0.2(4)	
sensitivity of timing interval	Each timer, astable (5)	T <sub>A</sub> = 25°C		0.3			0.15		%/V
into var	Timer 1 – Timer 2			±0.2			±0.1		
Output-pulse rise time	)	$C_L = 15 \text{ pF},$ $T_A = 25^{\circ}\text{C}$		100	300		100	200(4)	ns
Output-pulse fall time		$C_L = 15 \text{ pF},$ $T_A = 25^{\circ}\text{C}$		100	300		100	200(4)	ns

- (1) For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
- (2) Timing-interval error is defined as the difference between the measured value and the average value of a random sample from each process run.
- (3) Values specified are for a device in a monostable circuit similar to Figure 2, with the following component values:  $R_A = 2 \text{ k}\Omega$  to 100 k $\Omega$ ,  $C = 0.1 \,\mu\text{F}$ .
- (4) On products compliant to MIL-PRF-38535, this parameter is not production tested.
- (5) Values specified are for a device in an astable circuit similar to Figure 1, with the following component values: R<sub>A</sub> = 1 kΩ to 100 kΩ, C = 0.1 μF.



## **APPLICATION INFORMATION**



NOTE A: Bypassing the control-voltage input to ground with a capacitor might improve operation. This should be evaluated for individual applications.

Figure 1. Circuit for Astable Operation

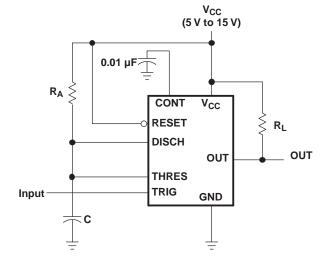


Figure 2. Circuit for Monostable Operation



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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
JM38510/10902BCA	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	JM38510 /10902BCA	Samples
NA556D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 105	NA556	
NA556DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 105	NA556	Samples
NA556N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 105	NA556N	Samples
NE556D	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	0 to 70	NE556	
NE556DBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	N556	Samples
NE556DR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	NE556	Samples
NE556N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	NE556N	Samples
NE556NSR	ACTIVE	SOP	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	NE556	Samples
SA556N	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SA556N	Samples
SE556J	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SE556J	Samples
SE556JB	ACTIVE	CDIP	J	14	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SE556JB	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.



## PACKAGE OPTION ADDENDUM

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**PACKAGE MATERIALS INFORMATION** 

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## TAPE AND REEL INFORMATION





	-
A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
NA556DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
NE556DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
NE556DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
NE556NSR	SOP	NS	14	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1



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#### \*All dimensions are nominal

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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
NA556DR	SOIC	D	14	2500	356.0	356.0	35.0
NE556DBR	SSOP	DB	14	2000	356.0	356.0	35.0
NE556DR	SOIC	D	14	2500	356.0	356.0	35.0
NE556NSR	SOP	NS	14	2000	356.0	356.0	35.0

## **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
NA556N	N	PDIP	14	25	506	13.97	11230	4.32
NA556N	N	PDIP	14	25	506	13.97	11230	4.32
NE556N	N	PDIP	14	25	506	13.97	11230	4.32
NE556N	N	PDIP	14	25	506	13.97	11230	4.32
SA556N	N	PDIP	14	25	506	13.97	11230	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-150.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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